

ISL9K460P3

4A, 600V Stealth™ Dual Diode

General Description

The ISL9K460P3 is a Stealth™ dual diode optimized for low loss performance in high frequency hard switched applications. The Stealth™ family exhibits low reverse recovery current (I_{RRM}) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RRM} and short t_a phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the Stealth $^{\rm TM}$ diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Formerly developmental type TA49408.

Features

•	Soft Recovery $t_b / t_a > 3$
•	Fast Recovery t_{rr} < 20ns
•	Operating Temperature
•	Reverse Voltage

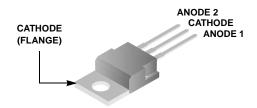
Avalanche Energy Rated

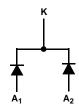
Applications

- Switch Mode Power Supplies
- · Hard Switched PFC Boost Diode
- · UPS Free Wheeling Diode
- · Motor Drive FWD
- SMPS FWD
- · Snubber Diode

Package Symbol

JEDEC TO-220AB





Device Maximum Ratings (per leg) T_C= 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V _R	DC Blocking Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current (T _C = 155°C)	4	Α
,	Total Device Current (Both Legs)	8	Α
I _{FRM}	Repetitive Peak Surge Current (20kHz Square Wave)	8	Α
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	50	Α
P _D	Power Dissipation	58	W
E _{AVL}	Avalanche Energy (0.5A, 80mH)	10	mJ
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to 175	°C
Tı	Maximum Temperature for Soldering		
T_{PKG}^{-}	Leads at 0.063in (1.6mm) from Case for 10s	300	°C
	Package Body for 10s, See Techbrief TB334	260	°C

CAUTION: Stresses above those listed in "Device Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Device Marking	Device	Package	Tape Width	Quantity
K460P3	ISL9K460P3	TO-220AC	N/A	50

Symbol	Parameter	Test	Conditions	Min	Тур	Max	Units
Off State	Characteristics						
I _R	Instantaneous Reverse Current	V _R = 600V	T _C = 25°C	-	-	100	μА
			T _C = 125°C	-	-	1.0	mA
On State	Characteristics						
V _F	Instantaneous Forward Voltage	I _F = 4A	T _C = 25°C	-	2.0	2.4	V
			T _C = 125°C	-	1.6	2.0	V
C _J	Unction Capacitance	V _R = 10V, I _F = 0	DA .	-	19	-	pF
Switchin	g Characteristics						
t _{rr}	Reverse Recovery Time	$I_F = 1A$, $d_{IF}/dt = 100A/\mu s$, $V_R = 30V$		-	17	20	ns
		$I_F = 4A$, $d_{IF}/dt = 100A/\mu s$, $V_R = 30V$		-	19	22	ns
t _{rr}	Reverse Recovery Time			-	17	-	ns
I_{RRM}	Maximum Reverse Recovery Current			-	2.6	-	Α
Q_{RR}	Reverse Recovery Charge			-	22	-	nC
t _{rr}	Reverse Recovery Time	$I_F = 4A$,		-	77	-	ns
S	Softness Factor (t _b /t _a)	$d_{IF}/dt = 200A/\mu$ $V_R = 390V$,	S,	-	4.2	-	
I _{RRM}	Maximum Reverse Recovery Current	$V_R = 390V$, $T_C = 125^{\circ}C$		_	2.8	-	Α
Q_{RR}	Reverse Recovery Charge	1C = 123 C		-	100	-	nC
t _{rr}	Reverse Recovery Time	I _F = 4A,		_	54	-	ns
S	Softness Factor (t _b /t _a)	$d_{IF}/dt = 400A/\mu s,$ $V_R = 390V,$ $T_C = 125^{\circ}C$		_	3.5	-	
I_{RRM}	Maximum Reverse Recovery Current			-	4.3	-	Α
Q_{RR}	Reverse Recovery Charge				110	-	nC
	Maximum di/dt during t _h			l -	500	1	A/µs

$R_{\theta JC}$	Thermal Resistance Junction to Case		-	-	2.6	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	TO-220	•	•	62	°C/W

Typical Performance Curves 175°C

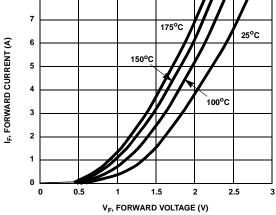
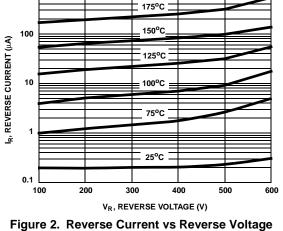


Figure 1. Forward Current vs Forward Voltage



600

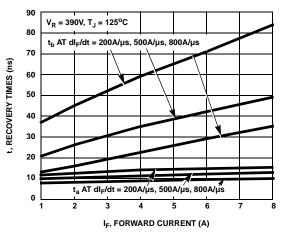


Figure 3. t_a and t_b Curves vs Forward Current

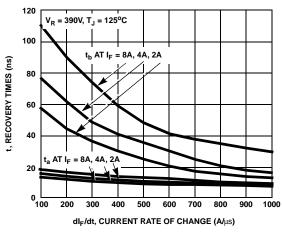


Figure 4. t_a and t_b Curves vs dI_F/dt

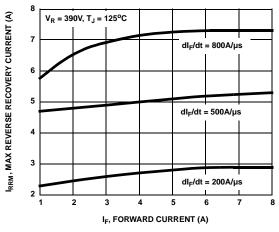


Figure 5. Maximum Reverse Recovery Current vs **Forward Current**

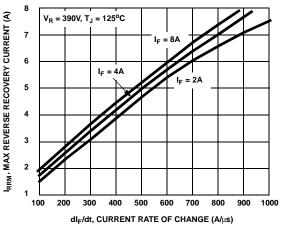
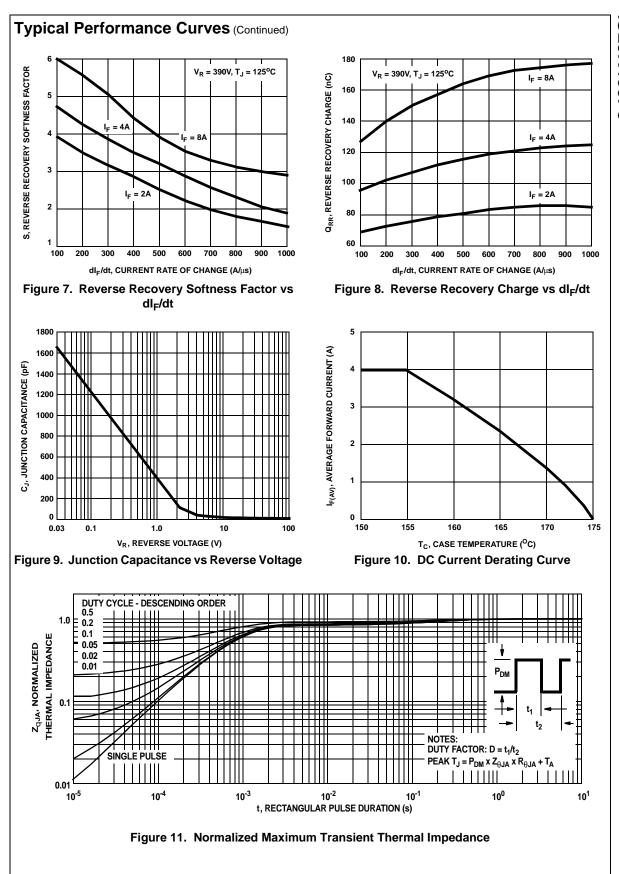
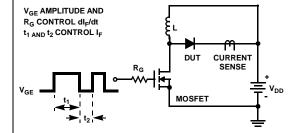


Figure 6. Maximum Reverse Recovery Current vs dl_F/dt



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Test Circuit and Waveforms



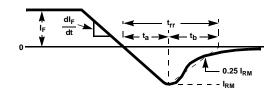


Figure 12. It_{rr} Test Circuit

Figure 13. t_{rr} Waveforms and Definitions

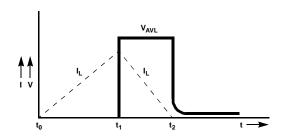


Figure 14. Avalanche Energy Test Circuit

Figure 15. Avalanche Current and Voltage Waveforms

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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic [®]
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EnSigna™	I ² C™	OCX™	RapidConfigure™	UHC™
Across the board	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franc	hise™	OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable A	ctive Droop™	OPTOPLANAR™	SMART START™	

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